

UMIL 80

80 Watts, 28 Volts, Class AB Defcom 200 - 500 MHz

GENERAL DESCRIPTION

The UMIL80 is a double input matched COMMON EMITTER broadband transistor specifically intended for use in the 200-500 MHz frequency band. It may be operated in Class AB or C. Gold metallization and silicon diffused resistors ensure ruggedness and high reliability.

ABSOLUTE MAXIMUM RATINGS

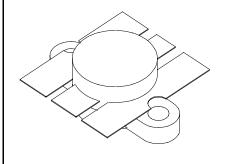
Maximum Power Dissipation @ 25°C 220 Watts

Maximum Voltage and Current

BVces Collector to Emiter Voltage 65 Volts
BVebo Emitter to Base Voltage 4.0 Volts
Ic Collector Current 12 A

Maximum Temperatures

Storage Temperature $-65 \text{ to } +150^{\circ}\text{C}$ Operating Junction Temperature $+200^{\circ}\text{C}$ CASE OUTLINE 55HV, Style 2



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg ¶c VSWR	Power Output Power Input Power Gain Efficiency Load Mismatch Tolerance	F = 400 MHz Vcc = 28 Volts	9.0 55	9.5	10 5:1	Watts Watts dB %

BVebo	Emitter to Base Breakdown	Ie = 5 mA	4.0			Volts
BVces	Collector to Emitter Breakdown	Ic = 20 mA	60			Volts
BVceo	Collector to Emitter Breakdown	Ie = 20 mA	31			Volts
BVcbo	Collector to Base Breakdown	Ic = 20 mA	60			Volts
Cob	Output Capacitance	Vcb=28 V, F= 1 MHz		80		pF
$\mathbf{h}_{ ext{FE}}$	DC - Current Gain	Vce = 5 V, Ic = 1 A	10			
θјс	Thermal Resistance				0.8	°C/W

Issue October 1998: Correct Case from Hu to HV

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POWER OUTPUT vs POWER INPUT

